SN54ABT16827, SN74ABT16827 20-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCBS220C - JUNE 1992 - REVISED MAY 1997

- Members of the Texas Instruments Widebus™ Family
- State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C
- High-Impedance State During Power Up and Power Down
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Lavout
- High-Drive Outputs (–32-mA I_{OH}, 64-mA I_{OL})
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) Package and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

The 'ABT16827 are noninverting 20-bit buffers composed of two 10-bit sections with separate output-enable signals. For either 10-bit buffer section, the two output-enable (10E1 and 10E2 or 20E1 and 20E2) inputs must both be low for the corresponding Y outputs to be active. If either output-enable input is high, the outputs of that 10-bit buffer section are in the high-impedance state.

SN54ABT16827 . . . WD PACKAGE SN74ABT16827 . . . DL PACKAGE (TOP VIEW)



When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT16827 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT16827 is characterized for operation from –40°C to 85°C.



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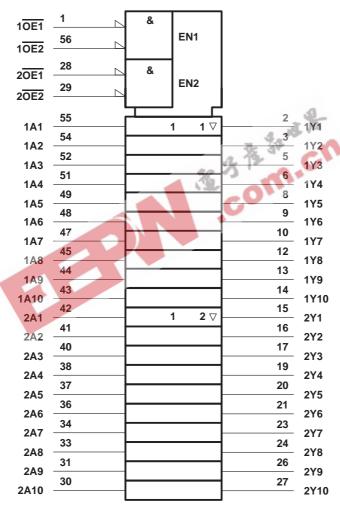
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SCBS220C - JUNE 1992 - REVISED MAY 1997

FUNCTION TABLE (each 10-bit section)

	OUTPUT		
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	X	Χ	Z
Х	Н	Χ	Z

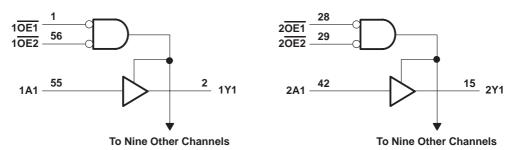
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, V _O	–0.5 V to 5.5 V
Current into any output in the low state, IO: SN54ABT16827	96 mA
SN74ABT16827	128 mA
Input clamp current, I _{IK} (V _I < 0)	–18 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DL package	
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51.

recommended operating conditions (see Note 3)

				SN54ABT16827		SN74ABT16827	
			MIN	MAX	MIN	MAX	UNIT
VCC	V _{CC} Supply voltage					5.5	V
V _{IH}	High-level input voltage		2		2		V
V _{IL} Low-level input voltage				0.8		0.8	V
VI	Input voltage				0	VCC	V
loh	IOH High-level output current					-32	mA
lOL	OL Low-level output current					64	mA
Δt/Δν	Input transition rise or fall rate	Control pins	200	4		4	ns/V
ΔυΔν	Data pins		Q.	10		10	113/ V
Δt/ΔVCC	Power-up ramp rate		200		200		μs/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

SN54ABT16827, SN74ABT16827 20-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCBS220C - JUNE 1992 - REVISED MAY 1997

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A = 25°C			SN54ABT16827		SN74ABT16827		UNIT	
				MIN	TYP [†]	MAX	MIN	MAX	MIN	MAX	ONIT	
٧ıK		$V_{CC} = 4.5 \text{ V},$	I _I = -18 mA			-1.2		-1.2		-1.2	V	
		$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5			
Vон		V _{CC} = 5 V,	$I_{OH} = -3 \text{ mA}$	3			3		3		V	
VОН		V _{CC} = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2				V	
		VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2			
VOL		V _{CC} = 4.5 V	$I_{OL} = 48 \text{ mA}$			0.55		0.55			V	
OL		VCC = 4.0 V	$I_{OL} = 64 \text{ mA}$			0.55				0.55	V	
V_{hys}					100						mV	
ΙĮ		$V_{CC} = 0$ to 5.5 $V_{I} = V_{CC}$ or GN				±1		±1		±1	μΑ	
$V_{CC} = 0 \text{ to } 2.1 \text{ V},$ $V_{O} = 0.5 \text{ V to } 2.7 \text{ V}, \overline{OE} = X$				±50		±50		±50	μΑ			
lozpD‡	$V_{CC} = 2.1 \text{ V to } 0,$ $V_{O} = 0.5 \text{ V to } 2.7 \text{ V}, \overline{OE} = X$		±50		48	±50		±50	μΑ			
lozh		$V_{CC} = 2.1 \text{ V} \text{ to } 5.5 \text{ V},$ $V_{O} = 2.7 \text{ V}, \text{ OE } \ge 2 \text{ V}$			3	10		10		10	μΑ	
lozL	OZL $V_{CC} = 2.1 \text{ V} \text{ to } 5.5 \text{ V}, \\ V_{O} = 0.5 \text{ V}, \overline{\text{OE}} \ge 2 \text{ V}$				W.	-10	(A)	-10		-10	μΑ	
V_{Off} $V_{CC} = 0$, V_{I}		V_I or $V_O \le 4.5 \text{ V}$			±100				±100	μΑ		
ICEX	Outputs high	$V_{CC} = 5.5 \text{ V},$	V _O = 5.5 V			50		50		50	μΑ	
ΙΟ§		$V_{CC} = 5.5 \text{ V},$	$V_0 = 2.5 \text{ V}$	-50	-100	-180	-50	-180	-50	-180	mA	
Outputs high		V 55V1 0				2		2		2		
ICC	Outputs low	$V_{CC} = 5.5 \text{ V}, I_{O}$ $V_{I} = V_{CC} \text{ or GN}$				32		32		32	mA	
	Outputs disabled					2		2		2		
ΔICC¶		V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND				1.5		1.5		1.5	mA	
Ci		$V_{I} = 2.5 \text{ V or } 0.5$	5 V		3						pF	
Co		V _O = 2.5 V or 0	.5 V		7.5						pF	

 $[\]begin{tabular}{l}^*$ On products compliant to MIL-PRF-38535, this parameter does not apply.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			SN54ABT16827		SN74ABT16827		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	А	Y	1	1.9	3.1	1	3.6	1	3.4	ns
^t PHL			1	2.1	3.7	1 0	4.5	1	4.2	
^t PZH	ŌĒ	Y	1	2.8	5	12	5.9	1	5.6	ns
^t PZL			1	2.8	4.9	3	5.8	1	5.5	
t _{PHZ}	ŌĒ	Y	2.4	4.5	6.5	2.4	6.8	2.4	6.6	
^t PLZ			1.6	3.7	5.7	1.6	7.1	1.6	6.1	

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[†] All typical values are at $V_{CC} = 5 \text{ V}$.

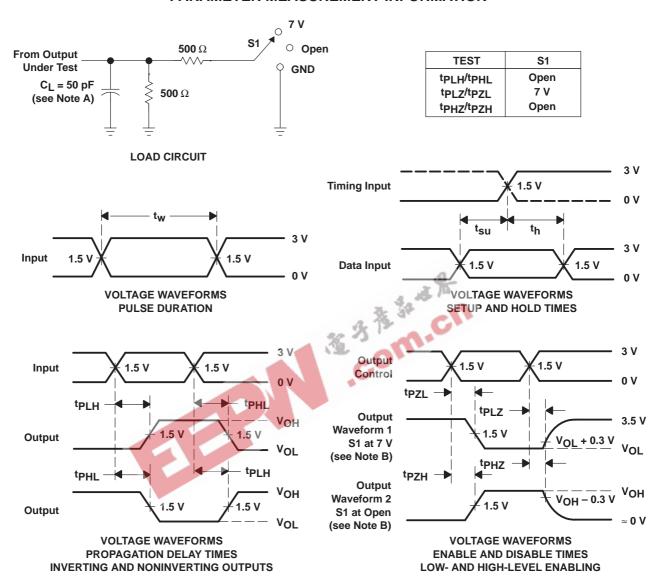
[‡]This parameter is characterized, but not production tested.

[§] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

SCBS220C - JUNE 1992 - REVISED MAY 1997

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \,\Omega$, $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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